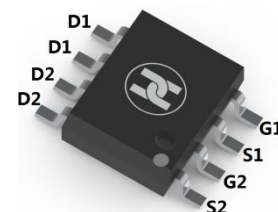
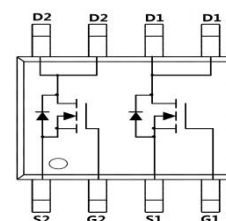


Dual N-Channel Enhancement Mode Field Effect Transistor
FEATURES

- $V_{DS}=30V, I_D=7.7A, R_{DS(ON)} \leq 21m\Omega @ V_{GS}=10V$
- Low on-resistance and low gate charge
- For synchronous rectifier applications
- Surface Mount device


SOP-8

MECHANICAL DATA

- Case: SOP-8
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.3 grams (approximate)

MAXIMUM RATINGS ($T_A = 25^\circ C$ unless otherwise noted)

Parameter		Symbol	Value	Unit
Drain-source voltage		V _{DS}	30	V
Gate-source voltage		V _{GS}	±20	V
Continuous drain current	T _A = 25°C	I _D	7.7	A
	T _A = 70°C		6.5	A
Pulsed drain current		I _{DM}	64	A
Power dissipation	T _A = 25°C	P _D	2	W
	T _A = 70°C		1.44	W
Thermal resistance from Junction to ambient		R _{θJA}	110	°C/W
Thermal resistance from Junction to Lead		R _{θJL}	50	°C/W
Junction temperature		T _J	150	°C
Storage temperature		T _{STG}	-55 ~+150	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Drain-Source breakdown voltage	$V_{(BR)DSS}^*$	30			V	$V_{GS}=0V, I_D=250\mu A$
Zero gate voltage drain current	I_{DSS}^*		0.004	1	μA	$V_{DS}=30V, V_{GS}=0V$
Gate-body leakage current	I_{GSS}^*			± 100	nA	$V_{DS}=0V, V_{GS}=\pm 20V$
Gate-threshold voltage	$V_{GS(th)}^*$	1.5	2.1	2.6	V	$V_{DS}=V_{GS}, I_D=250\mu A$
On-State Drain Current	$I_{D(ON)}$	64			A	$V_{DS}=5V, V_{GS}=4.5V$
Drain-source on-resistance	$R_{DS(ON)}^*$		16.8	21	m Ω	$V_{GS}=10V, I_D=7.7A,$
			24	29	m Ω	$V_{GS}=10V, I_D=7.7A, T_J=125^\circ C$
			23.4	30	m Ω	$V_{GS}=4.5V, I_D=5A$
Forward transconductance	g_{FS}		20		S	$V_{DS}=5V, I_D=7.7A$
Diode forward voltage	V_{SD}		0.75	1	V	$I_S=1A, V_{GS}=0V$
Diode forward current	I_S			2.4	A	
Input capacitance	C_{iss}		373	448	pF	$V_{DS}=15V, V_{GS}=0V, f=1MHz$
Output capacitance	C_{oss}		67		pF	
Reverse transfer capacitance	C_{rss}		41		pF	
Gate resistance	R_g		1.8	2.8	Ω	$V_{DS}=0V, V_{GS}=0V, f=1MHz$
Total gate charge	Q_g		3.5		nC	$V_{GS}=4.5V, V_{DS}=15V, I_D=7.7A$
			7.2	11	nC	$V_{GS}=10V, V_{DS}=15V, I_D=7.7A$
Gate-source charge	Q_{gs}		1.3		nC	
Gate-drain charge	Q_{gd}		1.7		nC	
Turn-on delay time	$t_{d(on)}$		4.5		nS	$V_{GS}=10V, V_{DS}=15V, R_{GEN}=3\Omega, R_L=1.95\Omega$
Turn-on rise time	t_r		2.7		nS	
Turn-off delay time	$t_{d(off)}$		14.9		nS	
Turn-off fall time	t_f		2.9		nS	
Body Diode Reverse Recovery Time	t_{rr}		10.5	12.6	nS	$I_F=7.7A, di/dt=100A/\mu s$
Body Diode Reverse Recovery Charge	Q_{rr}		4.5		nC	$I_F=7.7A, di/dt=100A/\mu s$

*Pulse test ; Pulse width $\leq 300\mu s$, Duty cycle $\leq 0.5\%$.

Dual N-Channel Enhancement Mode Field Effect Transistor

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

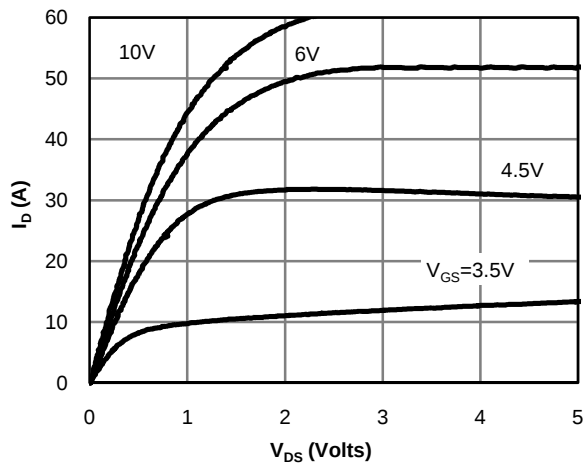


Fig 1: On-Region Characteristics

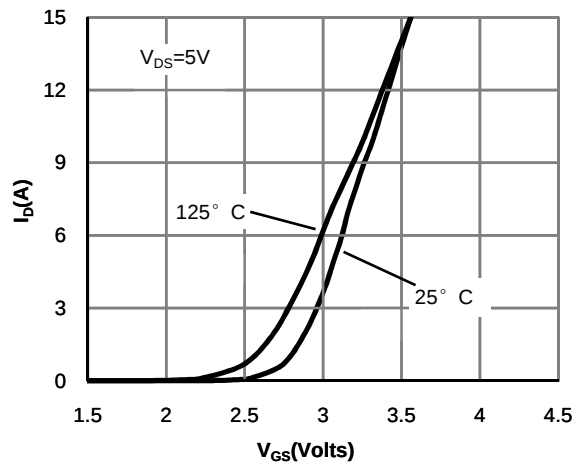


Figure 2: Transfer Characteristics

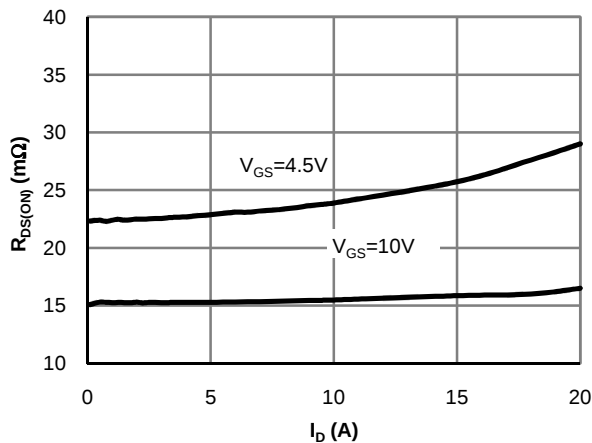


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

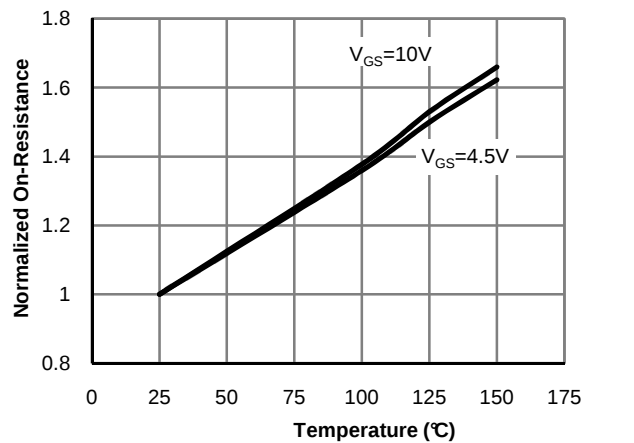


Figure 4: On-Resistance vs. Junction Temperature

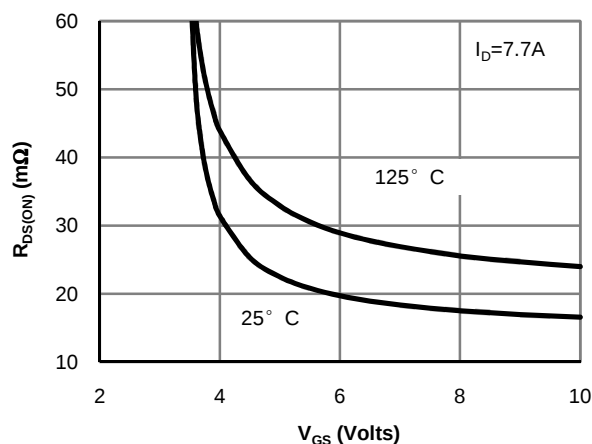


Figure 5: On-Resistance vs. Gate-Source Voltage

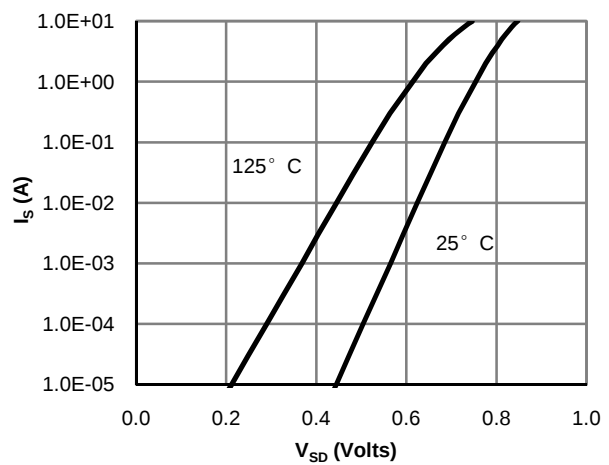
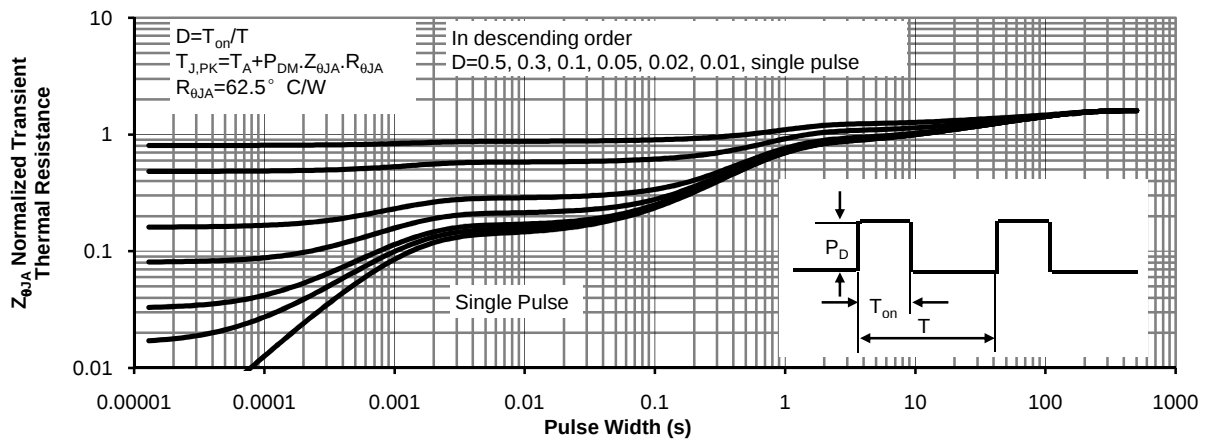
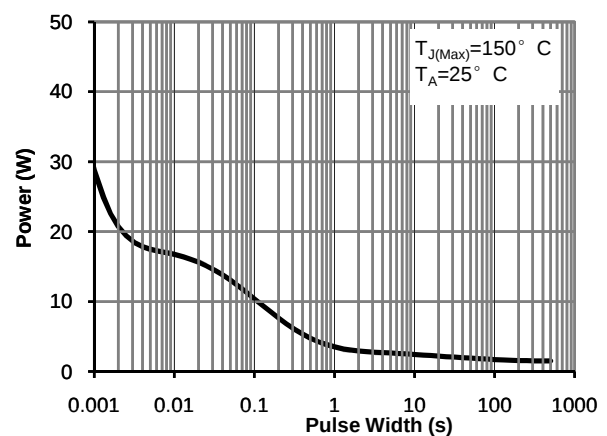
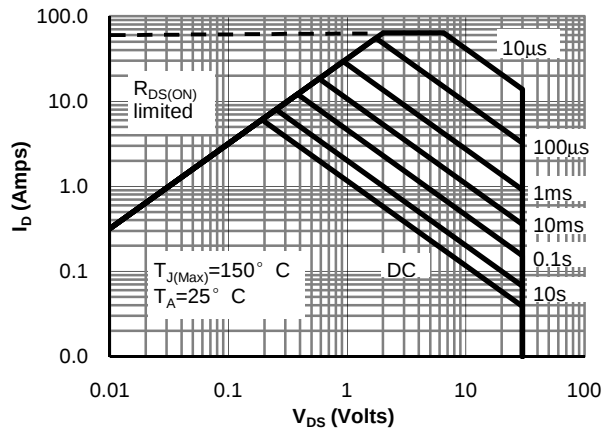
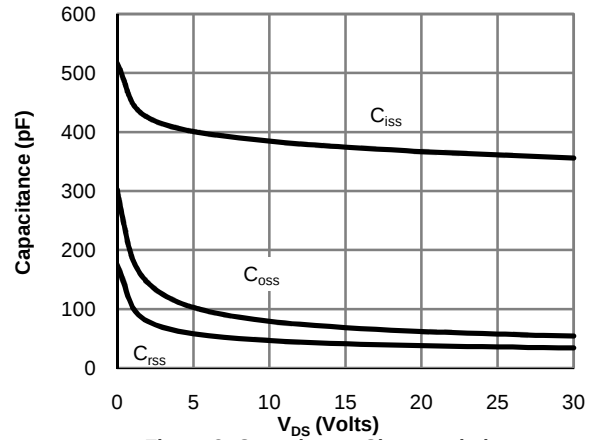
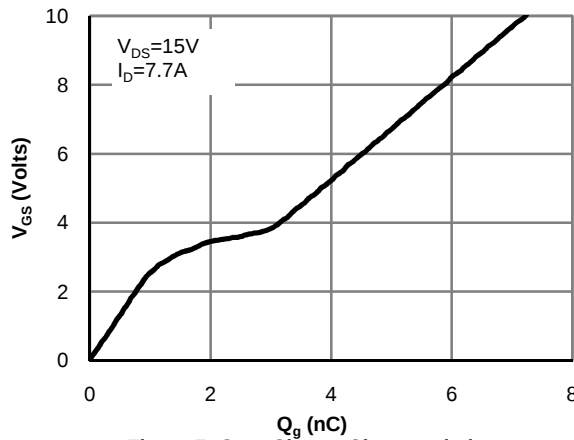
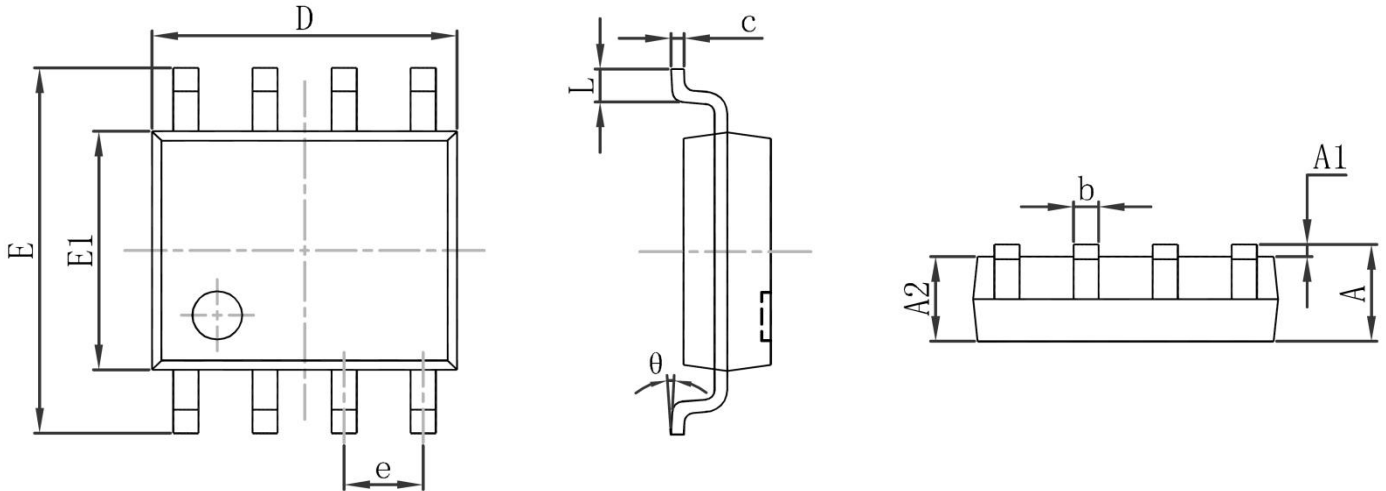


Figure 6: Body-Diode Characteristics

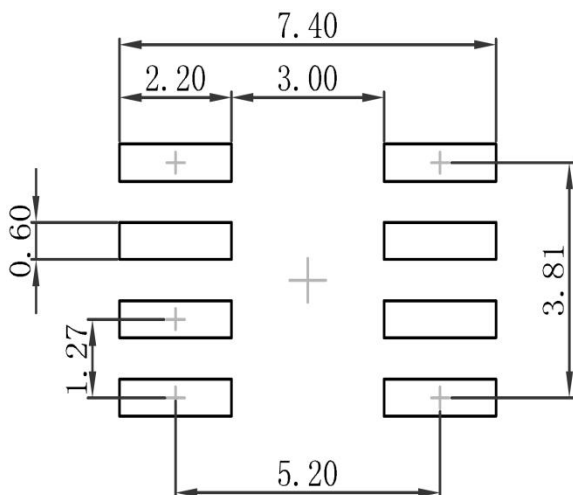
Dual N-Channel Enhancement Mode Field Effect Transistor

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



Dual N-Channel Enhancement Mode Field Effect Transistor
SOP-8 Package Outline Dimensions


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270(BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

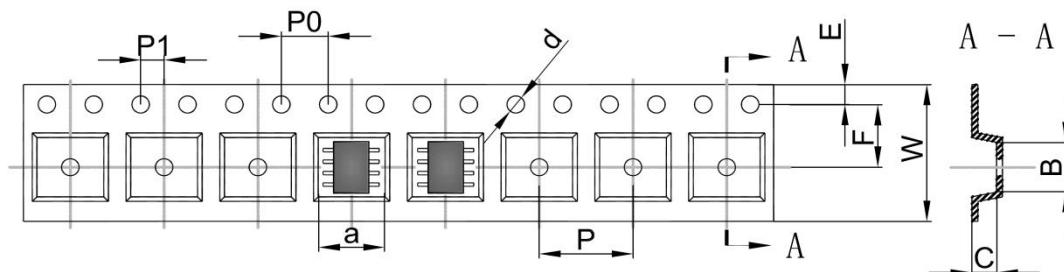
SOP-8 Suggested Pad Layout

Note:

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

Dual N-Channel Enhancement Mode Field Effect Transistor

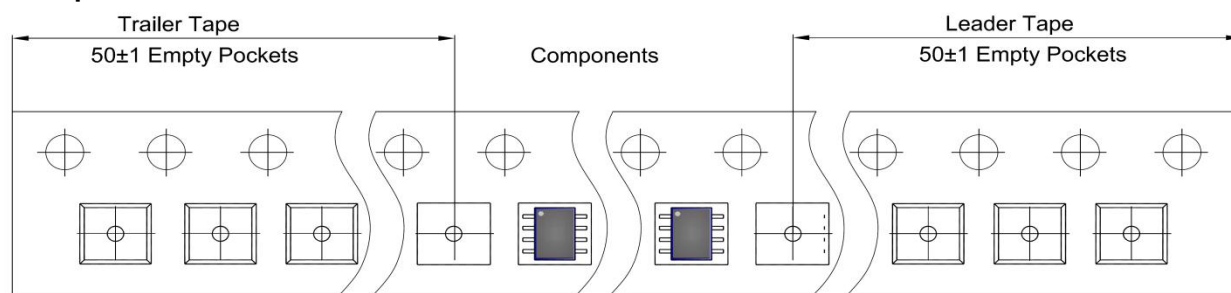
SOP-8 Tape and Reel

SOP-8 Embossed Carrier Tape

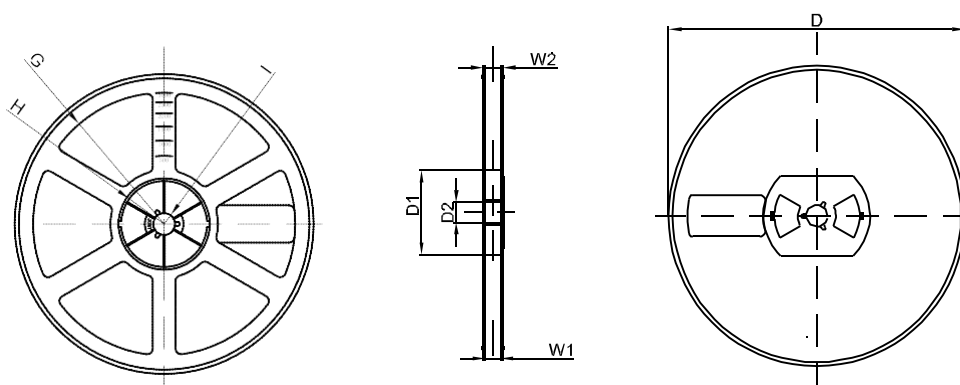


	DIMENSIONS ARE IN MILLIMETER									
TYPE	A	B	C	d	E	F	P0	P	P1	W
SOP-8	6.40	5.40	2.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SOP-8 Tape Leader and Trailer



SOP-8 Reel



	DIMENSIONS ARE IN MILLIMETER							
REEL OPTION	D	D1	D2	G	H	I	W1	W2
13" DIA	Ø330.00	100.00	13.00	R151.00	R56.00	R6.50	12.40	17.60
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1